Anode 2 🔿

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Top View

LINKS TO ADDITIONAL RESOURCES

Anode 1 O



PRIMARY CHARACTERISTICS				
I _{F(AV)}	30 A			
V _{RRM}	120 V			
I _{FSM}	250 A			
V_F at I_F = 30 A (T_A = 125 °C)	0.73 V			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Single			

eSMP[®] Series

SMPD (TO-263AC)

Bottom View

Cathode

FEATURES

Dual High-Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier Ultra Low $V_F = 0.46$ V at $I_F = 5$ A

Trench MOS Schottky technology generation 2

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- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** as marked

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL		UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	120	V		
Maximum average forward rectified current (fig. 1)	I _{F(AV)} ⁽¹⁾	30	A		
	I _{F(AV)} ⁽²⁾	6			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250	А		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +175	°C		

Notes

⁽¹⁾ With infinite heatsink

⁽²⁾ With recommended pad size, 2 oz FR4 PCB

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Available

FREE



V30DM120



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.55	-	V
	I _F = 15 A			0.73	-	
	I _F = 30 A			0.98	1.06	
	$I_F = 5 A$	T _A = 125 °C		0.46	-	
	I _F = 15 A			0.61	-	
	I _F = 30 A			0.73	0.81	
Reverse current at rated V_R per diode	V _R = 90 V	T _A = 25 °C	- I _R ⁽²⁾	0.01	-	mA
	v _R = 90 v	T _A = 125 °C		4	-	
	$V_{\rm R} = 120 {\rm V}$	T _A = 25 °C		-	1	IIIA
		T _A = 125 °C		8	20	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 $\,\%$ duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V30DM120	UNIT		
Typical thermal resistance	R _{θJC}	1.2	°C/W		
	R _{0JA} (1)(2)	48	- C/W		

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$ - junction-to-mount

⁽²⁾ Free air, without heatsink

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V30DM120-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
V30DM120HM3/I ⁽¹⁾	0.55		2000/reel	13" diameter plastic tape and reel	

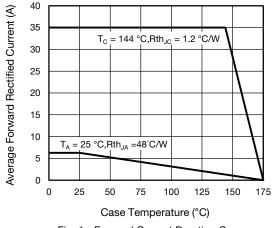
Note

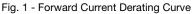
⁽¹⁾ AEC-Q101 gualified

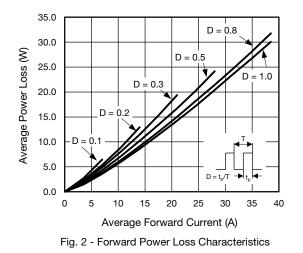


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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)







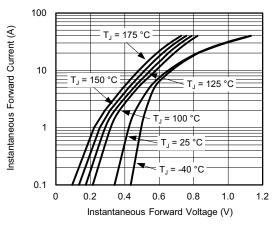
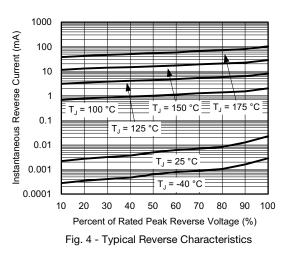
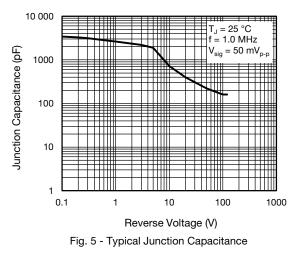
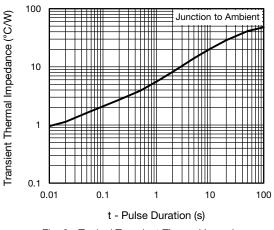


Fig. 3 - Typical Instantaneous Forward Characteristics









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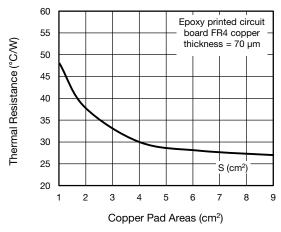
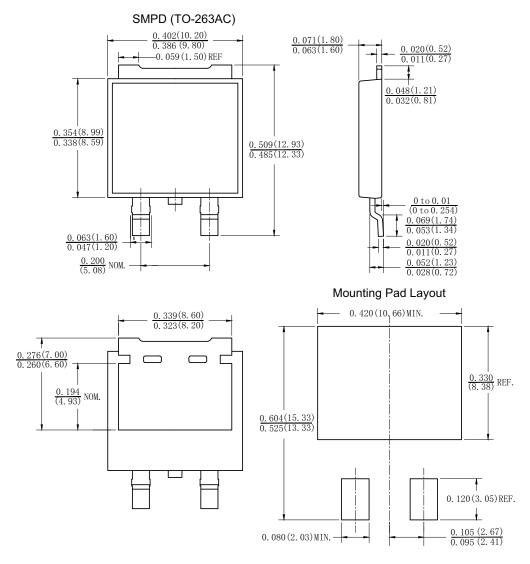


Fig. 7 - Thermal Resistance Junction-to-Ambient vs.Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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